

## Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

[Diodes Incorporated](#)  
[DSS5240Y-7](#)

For any questions, you can email us directly:

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Lead-free Green

**DSS5240Y**

**40V LOW  $V_{CE(sat)}$  PNP SURFACE MOUNT TRANSISTOR**

**Features**

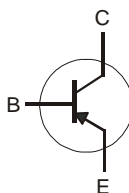
- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- Ultra Small Surface Mount Package
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free, "Green Device" (Note 2)
- ESD rating: 400V-MM, 8KV-HBM

**Mechanical Data**

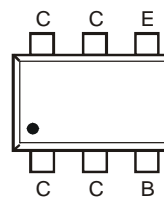
- Case: SOT-363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin annealed over Copper Plated Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.006 grams (approximate)



Top View



Device Symbol



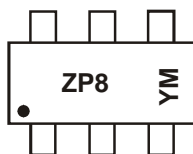
Top View  
Pin Out Configuration

**Ordering Information** (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DSS5240Y-7	ZP8	7	8mm	3,000

- Notes:
1. No purposefully added lead.
  2. Diodes Inc's "Green" Policy can be found on our website at <http://www.diodes.com>
  3. For packaging details, go to our website at <http://www.diodes.com>

**Marking Information**



ZP8 = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year (ex: W = 2009)  
 M = Month (ex: 9 = September)

Date Code Key

Year	2009	2010	2011	2012	2013	2014	2015	2016
Code	W	X	Y	Z	A	B	C	D

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

**Maximum Ratings** @ $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-40	V
Collector-Emitter Voltage	$V_{CEO}$	-40	V
Emitter-Base Voltage	$V_{EBO}$	-5	V
Collector Current - Continuous	$I_C$	-2	A
Peak Pulse Collector Current	$I_{CM}$	-3	A
Base Current (DC)	$I_B$	-300	mA
Peak Base Current	$I_{BM}$	-1	A

**Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4) @ $T_A = 25^\circ\text{C}$	$P_D$	625	mW
Thermal Resistance, Junction to Ambient (Note 4) @ $T_A = 25^\circ\text{C}$	$R_{\theta JA}$	200	$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

Notes: 4. Device mounted on FR-4 PCB, with minimum recommended pad layout.

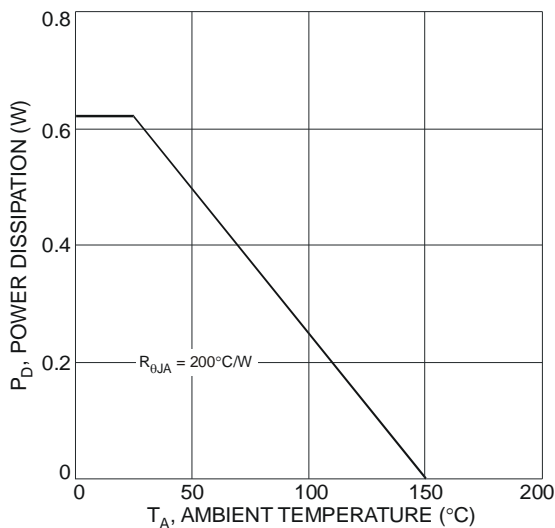


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 4)

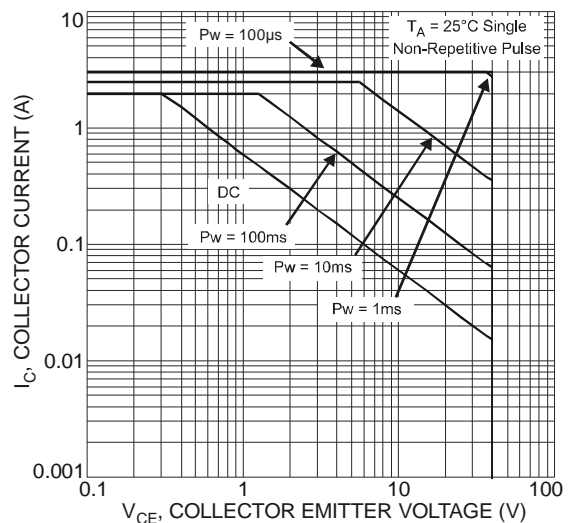


Fig. 2 Safe Operating Area

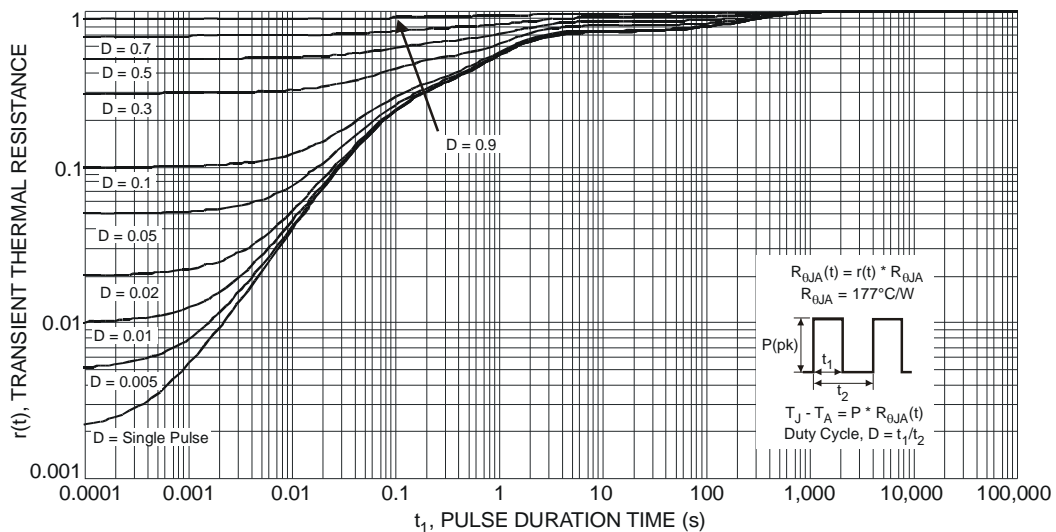


Fig. 3 Transient Thermal Response

**Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-40	—	—	V	I <sub>C</sub> = -100μA, I <sub>E</sub> = 0
Collector-Emitter Breakdown Voltage (Note 5)	BV <sub>CEO</sub>	-40	—	—	V	I <sub>C</sub> = -10mA, I <sub>B</sub> = 0
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5	—	—	V	I <sub>E</sub> = -100μA, I <sub>C</sub> = 0
Collector Cutoff Current	I <sub>CBO</sub>	—	—	-100	nA	V <sub>CB</sub> = -30V, I <sub>E</sub> = 0
Emitter Cutoff Current	I <sub>EBO</sub>	—	—	-100	nA	V <sub>CB</sub> = -30V, I <sub>E</sub> = 0, T <sub>A</sub> = 150°C
DC Current Gain (Note 5)	h <sub>FE</sub>	300	450	—	—	V <sub>CE</sub> = -2V, I <sub>C</sub> = -100mA
		260	380	—		V <sub>CE</sub> = -2V, I <sub>C</sub> = -500mA
		210	325	—		V <sub>CE</sub> = -2V, I <sub>C</sub> = -1A
		100	210	—		V <sub>CE</sub> = -2V, I <sub>C</sub> = -2A
		—	—	-100		I <sub>C</sub> = -100mA, I <sub>B</sub> = -1mA
Collector-Emitter Saturation Voltage (Note 5)	V <sub>CE(sat)</sub>	—	—	-110	mV	I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
		—	—	-225		I <sub>C</sub> = -750mA, I <sub>B</sub> = -15mA
		—	—	-225		I <sub>C</sub> = -1A, I <sub>B</sub> = -50mA
		—	—	-350		I <sub>C</sub> = -2A, I <sub>B</sub> = -200mA
		—	—	-220		I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Collector-Emitter Saturation Resistance	R <sub>CE(sat)</sub>	—	—	-220	mΩ	I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Base-Emitter Saturation Voltage (Note 5)	V <sub>BE(sat)</sub>	—	-1.0	-1.1	V	I <sub>C</sub> = -2A, I <sub>B</sub> = -200mA
Base-Emitter Turn On Voltage (Note 5)	V <sub>BE(on)</sub>	—	-0.67	-0.75	V	V <sub>CE</sub> = -2V, I <sub>C</sub> = -100mA
Output Capacitance	C <sub>obo</sub>	—	25	40	pF	V <sub>CB</sub> = -10V, f = 1.0MHz
Current Gain-Bandwidth Product	f <sub>T</sub>	100	220	—	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -50mA, f = 100MHz
Turn-On Time	t <sub>on</sub>	—	73	—	ns	V <sub>CC</sub> = -10V I <sub>C</sub> = -1A, I <sub>B1</sub> = I <sub>B2</sub> = -50mA
Delay Time	t <sub>d</sub>	—	27	—	ns	
Rise Time	t <sub>r</sub>	—	46	—	ns	
Turn-Off Time	t <sub>off</sub>	—	237	—	ns	
Storage Time	t <sub>s</sub>	—	195	—	ns	
Fall Time	t <sub>f</sub>	—	42	—	ns	

Notes: 5. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%.

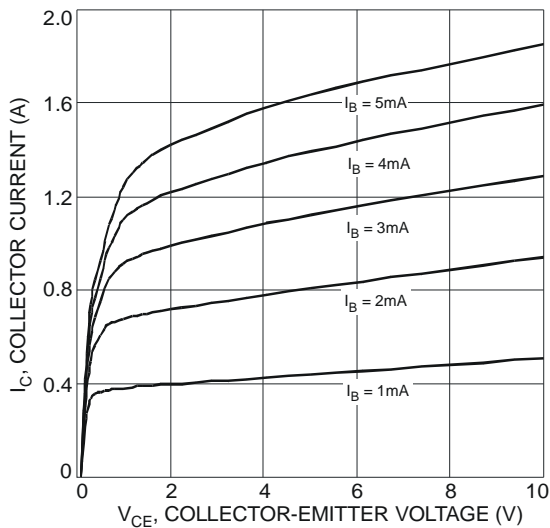


Fig. 4 Typical Collector Current vs. Collector-Emitter Voltage

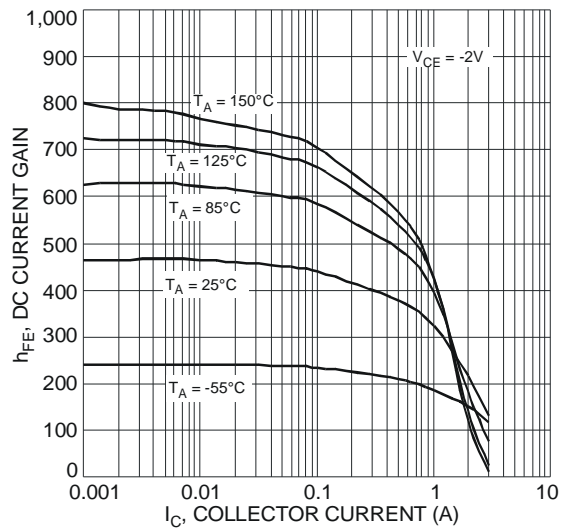


Fig. 5 Typical DC Current Gain vs. Collector Current

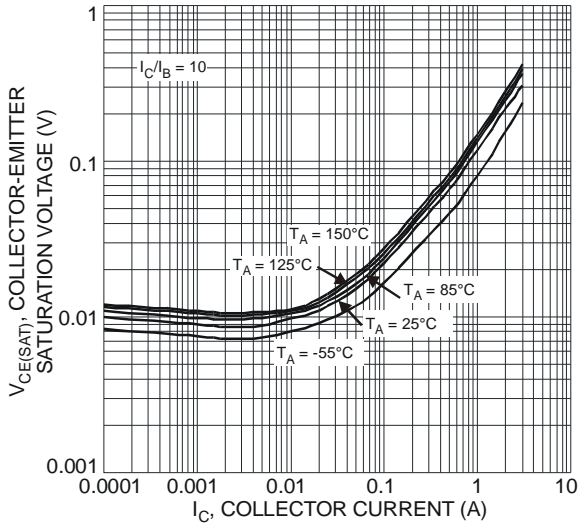


Fig. 6 Typical Collector-Emitter Saturation Voltage vs. Collector Current

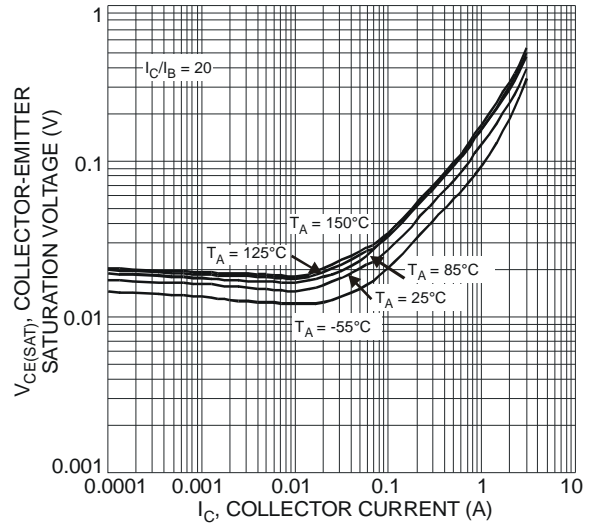


Fig. 7 Typical Collector-Emitter Saturation Voltage vs. Collector Current

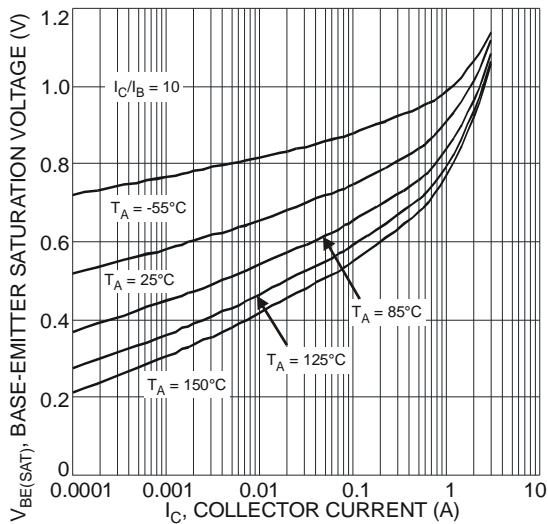


Fig. 8 Typical Base-Emitter Saturation Voltage vs. Collector Current

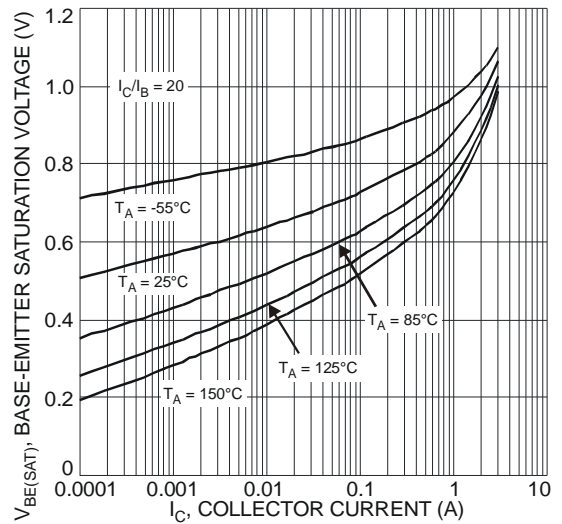


Fig. 9 Typical Base-Emitter Saturation Voltage vs. Collector Current

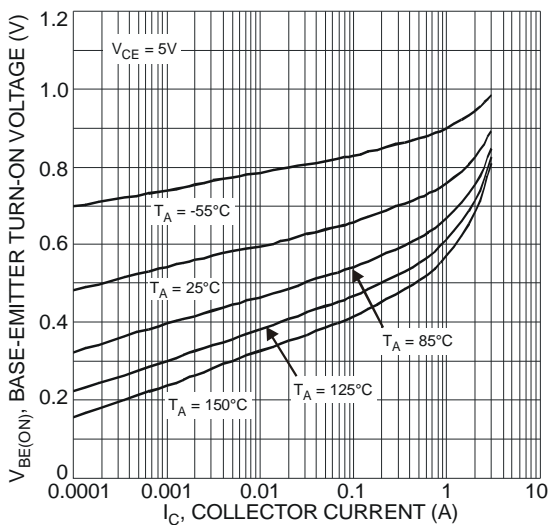
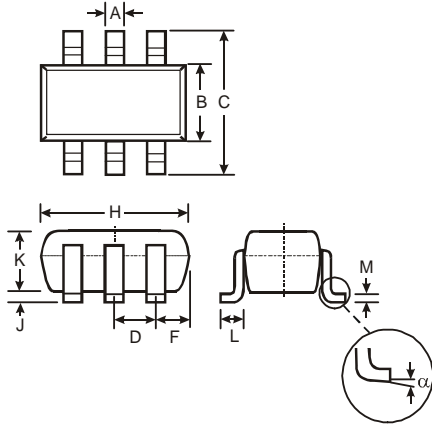


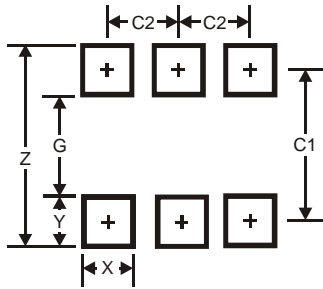
Fig. 10 Typical Base-Emitter Turn-On Voltage vs. Collector Current

**Package Outline Dimensions**



SOT-363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Typ	
F	0.40	0.45
H	1.80	2.20
J	0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.22
α	0°	8°
All Dimensions in mm		

**Suggested Pad Layout**



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65

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